FREE

Hyperfast Rectifier, 2 x 15 A FRED Pt[®] G5



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LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS							
I _{F(AV)} , per leg 15 A							
V _R , per leg	1200 V						
V _F at I _F at 125 °C, per leg	2.1 V						
t _{rr}	29 ns						
T _J max.	175 °C						
Package	3L TO-220AB						
Circuit configuration	Common cathode						

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching RoHS
 losses trade off
 HALOGEN
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: 3L TO-220AB

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

Polarity: as per marking device details

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage, per leg	V _{RRM}		1200	V			
Average rectified forward current, per leg	I _{F(AV)}	T _C = 98 °C, D = 0.50	15				
Repetitive forward current, per leg	I _{FRM}	T _C = 98 °C, D = 0.50, 20 kHz	30	А			
Non-repetitive peak surge current, per leg	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	110				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	IBOL TEST CONDITIONS MIN. TYP.				UNITS		
Breakdown voltage, blocking voltage, per leg	V _{BR} , V _R	I _R = 100 μA	1200	-	-			
Forward voltage, per leg	V _F	I _F = 15 A	-	2.5	3.3	V		
		I _F = 15 A, T _J = 125 °C	-	2.1	-			
Deverse leakage eurrent ner leg	I _R	$V_{R} = V_{R}$ rated	-	-	50			
Reverse leakage current, per leg		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA		
Junction capacitance, per leg	CT	V _R = 200 V	-	10	-	pF		
Series inductance, per leg	L _S	Measured to lead 5 mm from package body	-	8	-	nH		

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DYNAMIC RECOVERY CHARACTERISTICS (T_J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		I _F = 1.0 A, dI _F /dt =	100 A/ μ s, V _R = 30 V	-	29	44	
Reverse recovery time, per leg	t _{rr}	T _J = 25 °C		-	96	-	ns
		T _J = 125 °C		-	137	-	
Peak recovery current, per leg	I	T _J = 25 °C	l _F = 10 A dl _F /dt = 600 A/µs	-	11.5	-	A
	I _{RRM}	T _J = 125 °C	$V_{\rm R} = 400 \text{ V}$	-	16	-	
Reverse recovery charge, per leg	Q _{rr}	T _J = 25 °C		-	375	-	nC
Reverse recovery charge, per leg		T _J = 125 °C		-	900	-	
Poverse recovery time, per lea	+	T _J = 25 °C	I _F = 15 A dI _F /dt = 1000 A/µs V _R = 800 V	-	77.5	-	ns
Reverse recovery time, per leg	t _{rr}	T _J = 125 °C		-	106	-	
Poak racovary ourrant par lag	1	T _J = 25 °C		-	21	-	A
Peak recovery current, per leg	I _{RRM}	T _J = 125 °C		-	29	-	
Reverse recovery charge, per leg	0	T _J = 25 °C		-	680	-	
	Q _{rr}	T _J = 125 °C		-	1600	-	nC

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case, per leg	R _{thJC}		-	-	1.7	°C/W		
			-	2.0	-	g		
Weight			-	0.07	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style 3L TO-220AB	C5TX3012					



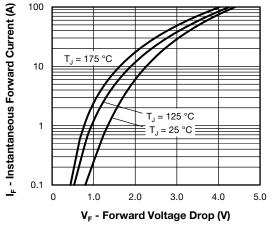


Fig. 1 - Forward Voltage Drop Characteristics, Per Leg

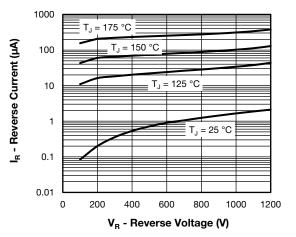


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg

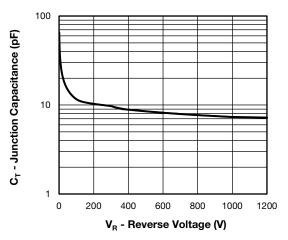
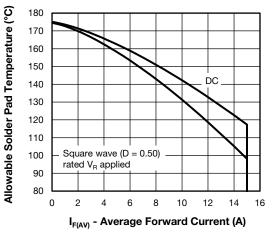
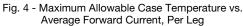
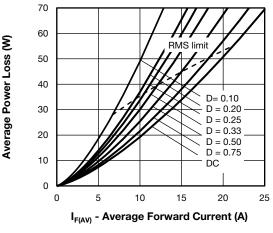
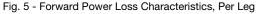


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg









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 3
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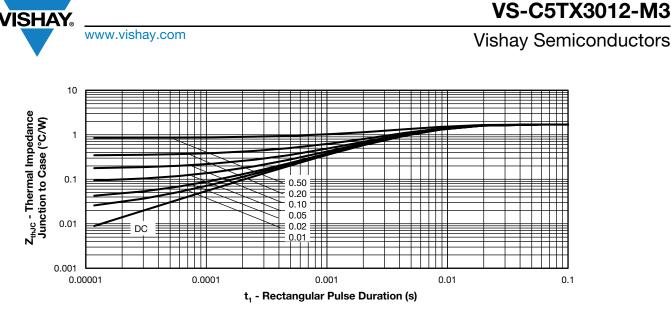


Fig. 6 - Transient Thermal Impedance, Junction to Case, Per Leg

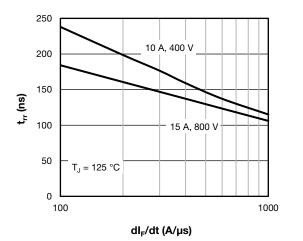


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt, Per Leg

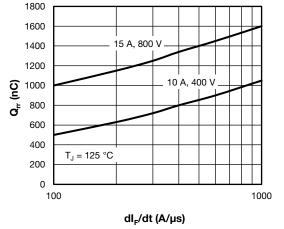


Fig. 8 - Typical Stored Charge vs. dl_F/dt, Per Leg

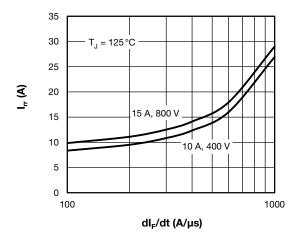
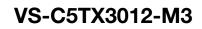


Fig. 9 - Typical Recovery Current vs. dI_F/dt, Per Leg





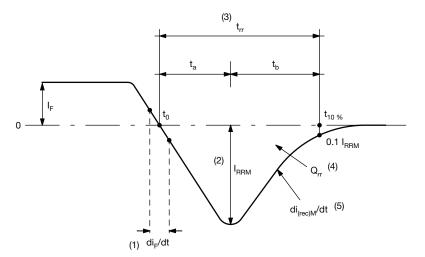


Fig. 10 - Reverse Recovery Waveform and Definitions

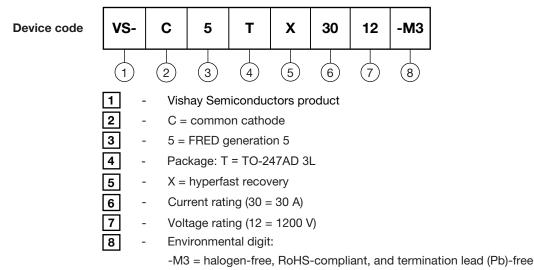
Notes

- (1) di_F/dt rate of change of current through zero crossing
- ⁽²⁾ I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}~~Q_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-C5TX3012-M3	50	1000	Antistatic plastic tube			

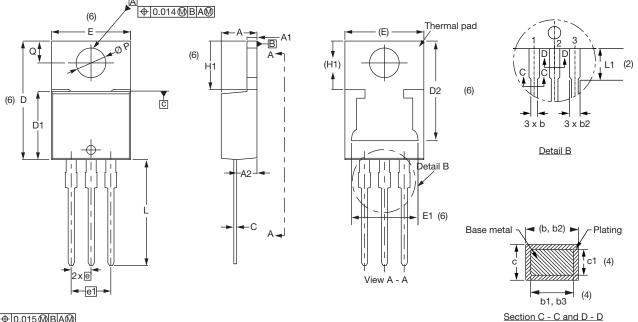
LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96154
Part marking information	www.vishay.com/doc?95028
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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕0.015@BA@





SYMBOL	MILLIN	IETERS	INC	NOTES	
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

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Conforms to JEDEC [®]	outline	TO-220AB

SYMBOL	MILLIN	MILLIMETERS		INCHES		
STINDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	11.68	13.30	0.460	0.524	6, 7	
Ш	10.11	10.51	0.398	0.414	3, 6	
E1	6.86	8.89	0.270	0.350	6	
е	2.41	2.67	0.095	0.105		
e1	4.88	5.28	0.192	0.208		
H1	6.09	6.48	0.240	0.255	6	
L	13.52	14.02	0.532	0.552		
L1	3.32	3.82	0.131	0.150	2	
ØР	3.54	3.91	0.139	0.154		
Q	2.60	3.00	0.102	0.118		

Notes

⁽²⁾ Lead dimension and finish uncontrolled in L1

- ⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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 $^{^{(1)}\,}$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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